








	<h2 style="color: red;">FQP13N10L</h2>
	<p>Hersteller-Teilenummer: FQP13N10L</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 100V 12.8A TO-220</p> <p>Datenblätter: 1.FQP13N10L.pdf 2.FQP13N10L.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 77361 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP13N10L
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 100V 12.8A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	77361 pcs Stock
Hersteller Standard Vorlaufzeit	5 Weeks
detaillierte Beschreibung	N-Channel 100V 12.8A (Tc) 65W (Tc) Through Hole
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	65W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12.8A (Tc)
Rds On (Max) @ Id, Vgs	180 mOhm @ 6.4A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	12nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	520pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	5V, 10V
Vgs (Max)	±20V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FQP13N10L ist neu im Original, Suche FQP13N10L Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP13N10L AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP13N10L: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP13N10L Fairchild/ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>	 <p>FQP13N10 Fairchild/ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>	 <p>FQP13N50C Fairchild/ON Semiconductor MOSFET N-CH 500V 13A TO-220</p>	 <p>FQP13N10C FSC FQP13N10C FSC</p>
 <p>FQP13N06L FQP13N06 Original FQP13N06L FQP13N06 Original</p>	 <p>FQP13N50C AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 13A TO-220</p>	 <p>FQP13N50 AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 12.5A TO-220</p>	 <p>FQP13N50 Fairchild/ON Semiconductor MOSFET N-CH 500V 12.5A TO-220</p>

heiße Teile

Mehr

⊗ FQP11N40C	↔ FQP11N40C	⇒ FQP11N50CF	D FQP11N50CF	↔ FQP11N60
⊕ FQP11N60C	⊗ FQP11N65C	D FQP11P06	⇒ FQP11P06	↔ FQP12N20
⊗ FQP12N60	⊕ FQP12N60	⊗ FQP12N60C	↔ FQP12N60C	↔ FQP12N65C
D FQP12P10	⊗ FQP12P10	⊕ FQP12P20	⊗ FQP12P20	↔ FQP13N06
⇒ FQP13N06	↔ FQP13N06L	⊗ FQP13N06L	⊕ FQP13N10	↔ FQP13N10
↔ FQP13N10L	⇒ FQP13N50	D FQP13N50	⊗ FQP13N50C	⊕ FQP13N50C
⊗ FQP13N60C	D FQP140N03	⇒ FQP140N03L	↔ FQP14N15	↔ FQP14N15
⊕ FQP14N30	⊗ FQP14N30	↔ FQP14N80	⇒ FQP14N80C	↔ FQP15N16
⊗ FQP15N30	⊕ FQP15N50	⊗ FQP15N60	D FQP15N65	↔ FQP15N80
↔ FQP15P12	⊗ FQP15P12	⊕ FQP16N15	⊗ FQP16N15	↔ FQP16N25

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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